Schottky diodes

Order code	Manufacturer code	Description
47-2534	SB130	SB130 SCHOTKY BARRIER DIODE
47-2536	SB140	SB140 SCHOTKY BARRIER DIODE

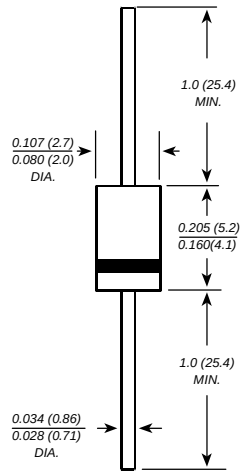
Sales: 01206 751166 **Technical: 01206 835555** **Fax: 01206 7551188**
Sales@rapidelec.co.uk **Tech@rapidelec.co.uk** **www.rapidelectronics.co.uk**

SB120 THRU SB1B0

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - *20 to 100 Volts* ***Forward Current -*** *1.0 Ampere*

DO-41



Dimensions in inches and (millimeters)

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High forward surge current capability
- High temperature soldering guaranteed:
  250℃/10 seconds, 0.375”(9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-41 molded plastic body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.012 ounce, 0.33 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	SB 120	SB 130	SB 140	SB 150	SB 160	SB 170	SB 180	SB 190	SB 1B0	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	70	80	90	100	VOLTS
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	49	56	63	70	VOLTS
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	70	80	90	100	VOLTS
Maximum average forward rectified current 0.375”(9.5mm) lead length (see fig.1)	$I_{(AV)}$	1.0									Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	40.0									Amps
Maximum instantaneous forward voltage at 1.0A	V_F	0.55			0.70		0.85				Volts
Maximum DC reverse current T_A=25℃	I_R	0.5									mA
at rated DC blocking voltage T_A=100℃		10.0			5.0						
Typical junction capacitance (NOTE 1)	C_J	110			80						pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0									°C/W
Operating junction temperature range	T_J,	-65 to +125			-65 to +150						°C
Storage temperature range	T_{STG}	-65 to +150									°C

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2.Thermal resistance from junction to ambient at 0.375”(9.5mm)lead length, P.C.B. mounted

RATINGS AND CHARACTERISTIC CURVES SB120 THRU SB1B0

FIG. 1- FORWARD CURRENT DERATING CURVE

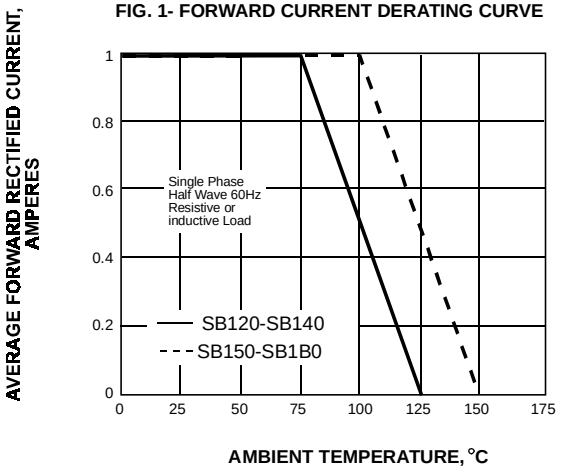


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

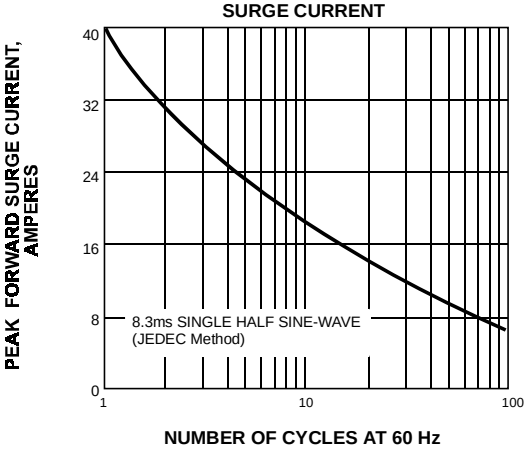


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

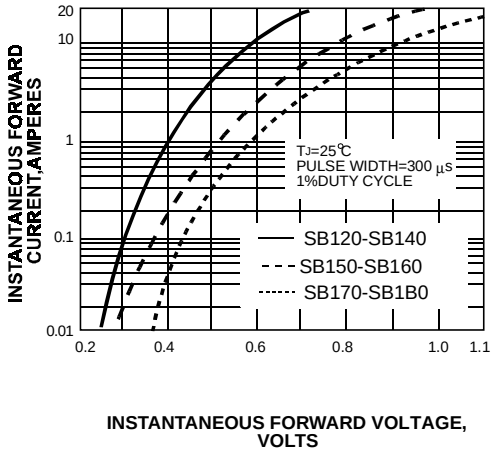


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

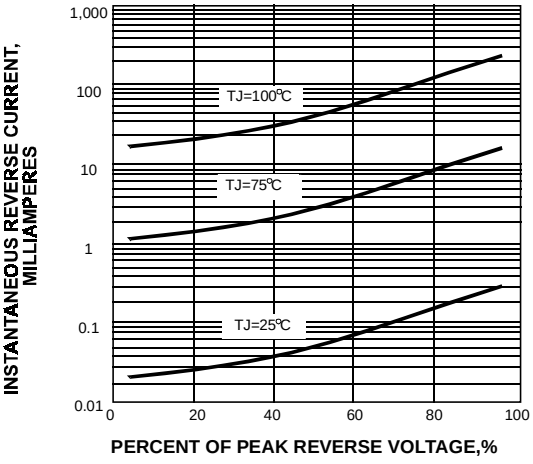


FIG. 5-TYPICAL JUNCTION CAPACITANCE

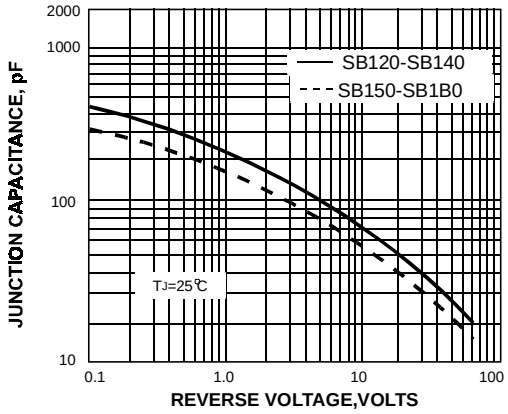


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE